

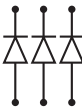
CMXD6001

**SURFACE MOUNT  
TRIPLE ISOLATED  
ULTRA LOW LEAKAGE  
SILICON SWITCHING DIODES**



www.centrasemi.com

**SUPERmini™**



**SOT-26 CASE**

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMXD6001 type contains three (3) Isolated Silicon Switching Diodes, manufactured by the epitaxial planar process, epoxy molded in a SUPERmini™ surface mount package, and designed for switching applications requiring extremely low leakage.

**MARKING CODE: X01**

**MAXIMUM RATINGS:** (T<sub>A</sub>=25°C)

Continuous Reverse Voltage	
Peak Repetitive Reverse Voltage	
Continuous Forward Current	
Peak Repetitive Forward Current	
Peak Forward Surge Current, tp=1.0μs	
Peak Forward Surge Current, tp=1.0s	
Power Dissipation	
Operating and Storage Junction Temperature	
Thermal Resistance	

SYMBOL		UNITS
V <sub>R</sub>	75	V
V <sub>R</sub> RM	100	V
I <sub>F</sub>	250	mA
I <sub>F</sub> RM	250	mA
I <sub>F</sub> SM	4.0	A
I <sub>F</sub> SM	1.0	A
P <sub>D</sub>	350	mW
T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C
θ <sub>JA</sub>	357	°C/W

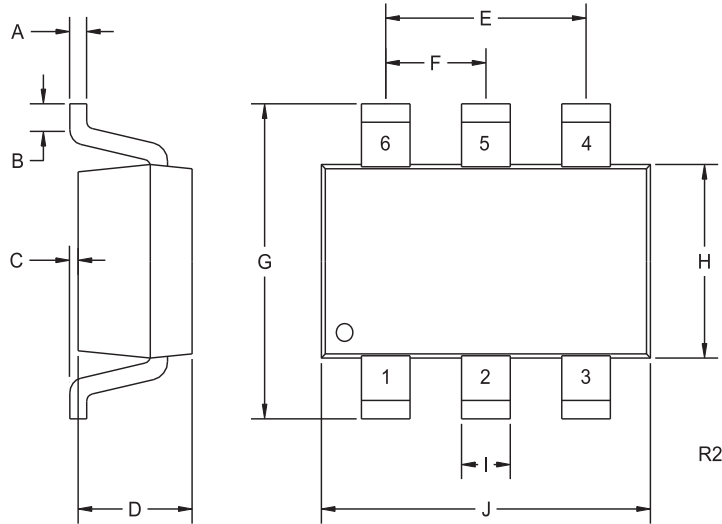
**ELECTRICAL CHARACTERISTICS PER DIODE:** (T<sub>A</sub>=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I <sub>R</sub>	V <sub>R</sub> =75V		500	pA
BV <sub>R</sub>	I <sub>R</sub> =100μA	100		V
V <sub>F</sub>	I <sub>F</sub> =1.0mA		0.85	V
V <sub>F</sub>	I <sub>F</sub> =10mA		0.95	V
V <sub>F</sub>	I <sub>F</sub> =100mA		1.1	V
C <sub>T</sub>	V <sub>R</sub> =0, f=1.0MHz		2.0	pF
t <sub>rr</sub>	I <sub>R</sub> =I <sub>F</sub> =10mA, I <sub>rr</sub> =1.0mA, R <sub>L</sub> =100Ω		3.0	μs

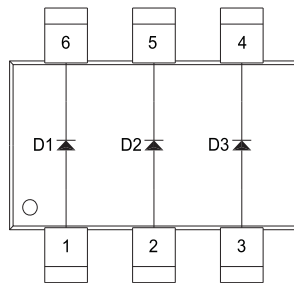
**CMXD6001**  
**SURFACE MOUNT**  
**TRIPLE ISOLATED**  
**ULTRA LOW LEAKAGE**  
**SILICON SWITCHING DIODES**



**SOT-26 CASE - MECHANICAL OUTLINE**



**PIN CONFIGURATION**



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.004	0.007	0.11	0.19
B	0.016	-	0.40	-
C	-	0.004	-	0.10
D	0.039	0.047	1.00	1.20
E	0.074	0.075	1.88	1.92
F	0.037	0.038	0.93	0.97
G	0.102	0.118	2.60	3.00
H	0.059	0.067	1.50	1.70
I	0.016		0.41	
J	0.110	0.118	2.80	3.00

SOT-26 (REV: R2)

**LEAD CODE:**

- 1) Anode D1
- 2) Anode D2
- 3) Anode D3
- 4) Cathode D3
- 5) Cathode D2
- 6) Cathode D1

**MARKING CODE: X01**

R4 (9-May 2011)

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